RESEARCH HIGHLIGHTS

Intramolecular spatial charge transfer enhances TADF efficiency

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Organic thermally activated delayed fluorescence (TADF) emitters have been advancing fast since 2012, behaving like the next-generation electroluminescent (EL) materials with the advantages of 100% exciton utilization efficiency, full-color emission tunability, and low cost^[1]. To obtain TADF, a common approach is to construct a twisted donor-acceptor (D–A) structure, minimizing the energy gap (ΔE_{ST}) between the lowest singlet (S₁) and triplet (T₁) via steric effect. However, this approach can only decrease the overlap between the highest occupied molecular orbitals (HOMOs) and the lowest unoccupied molecular orbitals (LUMOs) of the through-bond charge-transfer molecules along the linked axis, which is unidimensional (Fig. 1(a)). There is a "trade-off" hidden in the design of the TADF molecules: minimizing ΔE_{ST} can increase the rate constant of reverse intersystem crossing (k_{RISC}), but decrease the radiative rate constant $(k_{\rm R})^{[2]}$.

To control the "trade-off", a new D–A configuration was invented, in which the D and A moieties of TADF molecules are cofacially positioned to facilitate intramolecular through-space charge transfer (Fig. 1(b)). The overlap of the HOMO and LUMO of the molecules can be regulated by the spatial distance and the overlap area. Calculations revealed that the TADF emitters can offer efficient RISC and photolumines-cence quantum yield (PLQY) simultaneously. The organic light-emitting diodes (OLEDs) based on XPT gave a maximum external quantum efficiency (EQE_{max}) of 10.0%, which is higher than the theoretical limit of common fluorescent devices^[3] (Table 1).

By applying the intramolecular spatial charge transfer (ISCT) strategy (Fig. 1(c)), a series of innovative materials were developed in 2020, lighting the field of TADF-OLEDs. Liao *et al.* selected a rigid spiro-platform to control the spatial distance and relative orientation of donor (10-phenyl-9,10-di-hydroacridine) and acceptor (2,4,6-triphenyl-1,3,5-triazine) subunits. In the emitter DM-B with a cofacial configuration, the rigid backbone and shortened D–A distance of 3.16 Å resulted in a space-confined charge transfer, and the emitter gave a PLQY of 96% (λ_{PL} = 493 nm for doped film) due to strengthened ground-state electronic coupling and suppressed nonradiative decay channel. The corresponding TADF-OLED with a 50 wt% doping offered an EQE_{max} of 27.4% at 67 cd m⁻² with 0.1% efficiency roll-off at 1000 cd m^{-2[4]} (Table 1). Changing acceptor units with rigid dibenzothiophene sulfone and

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flexible diphenylsulphone uncovered that the rigidity of the linker and D–A distance play a crucial role in determining the optoelectronic properties of ISCT-TADF materials^[5]. To realize circularly polarized (CP) luminescence by ISCT, Jiang *et al.* grafted asymmetric donors within spiro frameworks. Efficient ISCT-TADF was obtained in the emitter SFOT due to shortened D–A distance of 2.90 Å (Fig. 1(c)). Benefiting 89.0% PLQY of SFOT, the (S)-SFOT-based CP-OLED delivered an enhanced EL performance with an EQE_{max} of 23.1% and a luminescence dissymmetry factor of $1.0 \times 10^{-3[6]}$.

Theoretically, direct spin-inversion from T₁ to S₁ is unproductive when they show the same CT nature. However, a fast spin-flipping would be triggered when a locally excited triplet state (³LE) intervenes in the CT states (³CT and ¹CT). Based on density functional theory calculations, an ultrafast RISC process was probed in ISCT systems by adjusting D–A distances and intersegment angles to generate appropriate ³LE states. Near-degenerate ¹CT, ³CT and ³LE states gave the emitter TpAT-tFFO a k_{RISC} of 1.2×10^7 s⁻¹, in which 9,9-dimethyl-9,10-dihydroacridine donor and 2,4-diphenyl-1,3,5-triazine acceptor were introduced to 1 and 8 positions of triptycene. The corresponding sky-blue device offered an EQE_{max} of $19.2\%^{[7]}$ (Table 1).

Yang et al. designed an ISCT molecule by attaching guasiplanar donor (DPXZ: a rigid O-bridged triphenylamine) and acceptor (BO: a rigid O-bridged triphenylborane) to 1 and 9 positions of carbazole to form a close cofacial π - π stacking (3.2–3.6 Å). The PLQY of the emitter DPXZ-BO (Fig. 1(c)) was ~99.0%, and the 30 wt% doped device gave an EQE_{max} of 23.96% with the Commission Internationale de l'Eclairage (CIE) coordinate of (0.26, 0.58)^[8]. Recently, Jiang et al. developed more advanced ISCT-TADF emitters with a D/A/D structure to form multilayer π - π stacking in one molecule. Efficient ISCT was attained in the D/A/D system due to the enforced face-to-face orientation. The D-A distances for DM-BD1 and DM-BD2 (Fig. 1(c)) were shorter than that of their analogue DM-B, resulting in high PLQY of 94.2% and 92.8%, respectively. The devices based on DM-BD1 and DM-BD2 exhibited EQE_{max} of 28.0% and 26.6%^[9], respectively, which are higher than that for DM-B-based device^[4] (Table 1). These results indicate that regulating the conformation of D and A units as well as $\pi - \pi$ interactions between them could improve the performance of ISCT-TADF emitters.

In summary, the ISCT strategy helps to obtain highly efficient TADF emitters *via* accelerating the RISC from T₁ to S₁. The "trade-off" between k_{RISC} and k_{R} in through-bond CT systems can be balanced by using ISCT approach. More highly efficient TADF emitters will be developed *via* chemical tuning of

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Fig. 1. (Color online) (a) Through-bond charge transfer. Reproduced with permission^[3], Copyright 2017, American Chemical Society. (b) Throughspace charge transfer. Reproduced with permission^[9], Copyright 2021, Wiley-VCH. (c) The ISCT-TADF emitters^[3, 4, 6–9]. *d*: D–A distance. Reproduced with permissions^[6, 8], Copyright 2020, American Chemical Society and Wiley-VCH.

Table 1. ISCT-TAD	⁼ emitters	cited in	this article.
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Emitter	$\lambda_{\rm PL}$ (nm)	PLQY (%)	$k_{\rm RISC}$ (s ⁻¹)	<i>k</i> _R (s ⁻¹)	HOMO (eV)	LUMO (eV)	$\Delta E_{\rm ST}$ (eV)	EL performance		Def
								$\lambda_{\rm EL}/{\rm CIE} ({\rm nm})/(x, y)$	EQE _{max} (%)	- Rel.
XPT	566	66.0	_	_	-4.99	-3.15	0.001	584/-	10.0	[<mark>3</mark>]
DM-B	493	78.0	$0.18 imes 10^{6}$	$6.75 imes 10^{6}$	-6.38	-0.71	0.170	488/(0.20, 0.44)	27.4	[4]
SFOT	512	89.0	1.17×10^{5}	-	-5.13	-2.91	0.053	508/-	23.1	[<mark>6</mark>]
TpAT-tFFO	485	98.0	1.20×10^{7}	1.10×10^{6}	-6.47	-0.90	0.019	498/(0.20, 0.44)	19.2	[7]
DPXZ-BO	511	99.0	2.10×10^{5}	$2.36 imes 10^{6}$	-5.08	-1.98	0.030	-/(0.26, 0.58)	23.9	[<mark>8</mark>]
DM-BD1	495	94.2	$0.29 imes 10^{6}$	$4.41 imes 10^{6}$	-5.36	-1.99	0.050	-/(0.21, 0.47)	28.0	[<mark>9</mark>]
DM-BD2	495	92.8	0.31 × 10 ⁶	3.03×10^{6}	-5.30	-1.95	0.040	-/(0.20, 0.46)	26.6	[<mark>9</mark>]

ISCT molecules, i.e. modulating the energy levels and conformations of D and A units, and optimizing their spatial alignments.

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